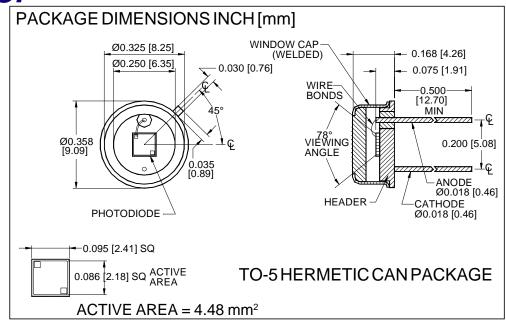
PHOTONIC DETECTORS INC.

Silicon Photodiode, Blue Enhanced Photovoltaic Type PDB-V105





FEATURES

- Low noise
- Blue enhanced
- High shunt resistance
- High response

DESCRIPTION

The **PDB-V105** is a silicon, PIN planar diffused, blue enhanced photodiode. Ideal for low noise photovoltaic applications. Packaged in a hermetic TO-5 metal can with a flat window.

APPLICATIONS

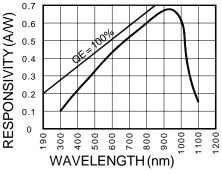
- Instrumentation
- Industrial measurement
- Exposure sensor
- Flame monitor

ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)

SYMBOL	PARAMETER M		MAX	UNITS	
V _{BR}	Reverse Voltage		75	V	
T _{STG}	Storage Temperature	-55	+150	∘C	
То	Operating Temperature Range	-40	+125	°C	
Ts	Soldering Temperature*		+240	∘C	
IL	Light Current		0.5	mA	

^{*1/16} inch from case for 3 secs max

SPECTRAL RESPONSE



ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

SYMBOL	CHARACTERISTIC	TESTCONDITIONS	MIN	TYP	MAX	UNITS
Isc	Short Circuit Current	H = 100 fc, 2850 K	30	50		μ A
ΙD	Dark Current	$H = 0, V_R = 10 V$		200	400	рА
Rsh	Shunt Resistance	$H = 0, V_R = 10 \text{ mV}$	2	5		GΩ
TC Rsh	RSH Temp. Coefficient	$H = 0, V_R = 10 \text{ mV}$		-8		%/°C
Сл	Junction Capacitance	$H = 0, V_R = 0 V^{**}$		500		pF
λrange	Spectral Application Range	Spot Scan	350		1100	nm
λр	Spectral Response - Peak	Spot Scan		950		nm
V _{BR}	Breakdown Voltage	I = 10 μA	10	50		V
NEP	Noise Equivalent Power	V _R = 10 mV @ Peak		.5x10 ⁻¹⁴		W/ √Hz
tr	Response Time	$RL = 1 K\Omega V_R = 0 V$		500		nS